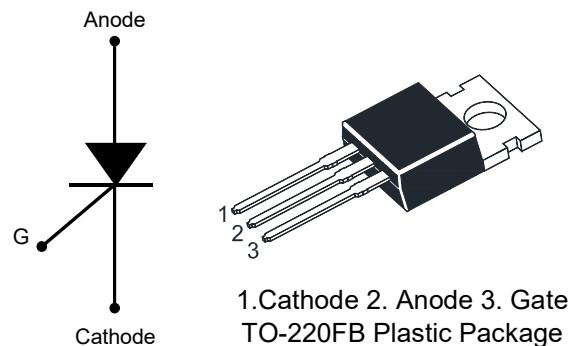


BT12-500-HAF

Planar Unidirection Thyristors

Features

- Halogen and Antimony Free(HAF), RoHS compliant

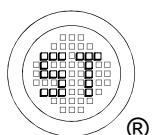


Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Value | Unit |
|--|--------------|---------------|------------------------|
| Repetitive Peak off-State Voltage | V_{DRM} | 500 | V |
| Repetitive Peak Reverse Voltage | V_{RRM} | 500 | V |
| RMS on-State Current All conduction angles | $I_{T(RMS)}$ | 12 | A |
| Peak Non-repetitive Surge Current (Half sine wave, $T_j = 25^\circ\text{C}$ prior to surge) | I_{TSM} | 120 | A |
| Circuit Fusing Considerations | I^2t | 50 | A^2s |
| Critical Rate-of-Rise of on-State Current at $I_{TM} = 20 \text{ A}$, $I_G = 50 \text{ mA}$, $dI_G/dt = 50 \text{ mA/ms}$ | dl/dt | 50 | $\text{A}/\mu\text{s}$ |
| Peak Gate Current | I_{GM} | 2 | A |
| Peak Gate Voltage | V_{GM} | 5 | V |
| Peak Reverse Gate Voltage | V_{RGM} | 5 | V |
| Peak Gate Power Dissipation (Over any 20 ms period) | P_{GM} | 5 | W |
| Average Gate Power Dissipation | $P_{G(AV)}$ | 0.5 | W |
| Operating Junction Temperature Range | T_J | 125 | $^\circ\text{C}$ |
| Storage Temperature Range | T_{Stg} | - 40 to + 150 | $^\circ\text{C}$ |

Thermal Characteristics

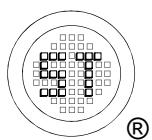
| Parameter | Symbol | Typ. | Unit |
|---|-----------------|------|---------------------------|
| Thermal Resistance from Junction to Ambient | $R_{\theta JA}$ | 60 | $^\circ\text{C}/\text{W}$ |



BT12-500-HAF

Characteristics at $T_j = 25^\circ\text{C}$ unless otherwise specified

| Parameter | Symbol | Min. | Max. | Unit |
|---|----------------------------------|------|------|------------|
| Peak Forward or Reverse Blocking Current at $V_{\text{DRM}} / V_{\text{RRM}}$, $T_j = 125^\circ\text{C}$ | $I_{\text{DRM}}, I_{\text{RRM}}$ | - | 0.5 | mA |
| Peak Forward on-State Voltage at $I_T = 23 \text{ A}$ | V_T | - | 1.75 | V |
| Gate Trigger Current at $V_D = 12 \text{ V}$, $I_T = 100 \text{ mA}$ | I_{GT} | - | 15 | mA |
| Holding Current at $V_D = 12 \text{ V}$, $I_{\text{GT}} = 100 \text{ mA}$ | I_H | - | 20 | mA |
| Latching Current at $V_D = 12 \text{ V}$, $I_{\text{GT}} = 100 \text{ mA}$ | I_L | - | 40 | mA |
| Gate Trigger Voltage at $V_D = 12 \text{ V}$, $I_T = 100 \text{ mA}$ at $V_D = 500 \text{ V}$, $I_T = 100 \text{ mA}$, $T_j = 125^\circ\text{C}$ | V_{GT} | 0.25 | 1.5 | V |
| Critical rate of rise of voltage at $V_D = 67\% V_{\text{DRM}}$ Gate Open, $T_j = 125^\circ\text{C}$ | dV/dt | 50 | - | V/ μ s |



Electrical Characteristics Curves

Fig.1 RMS on-State Current vs. T_a

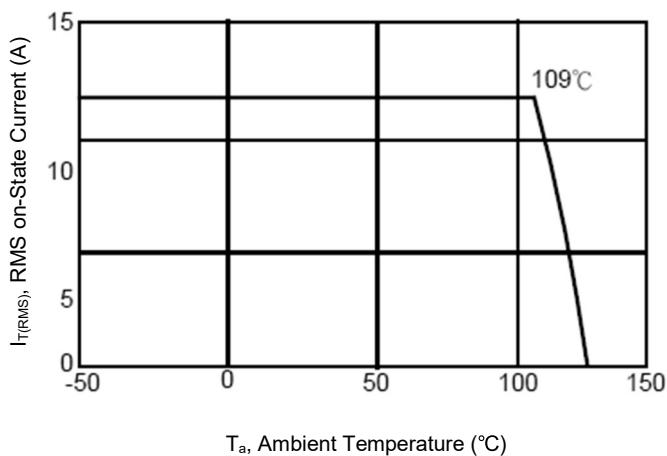


Fig.2 Surge Peak on-State Current vs. time

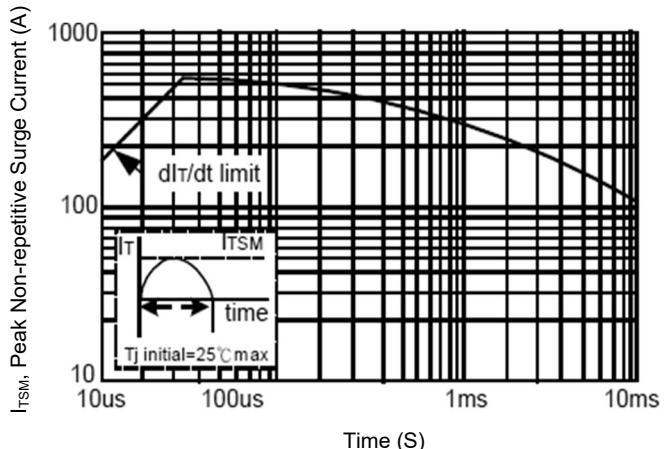


Fig.3 RMS on-State Current vs. Surge duration

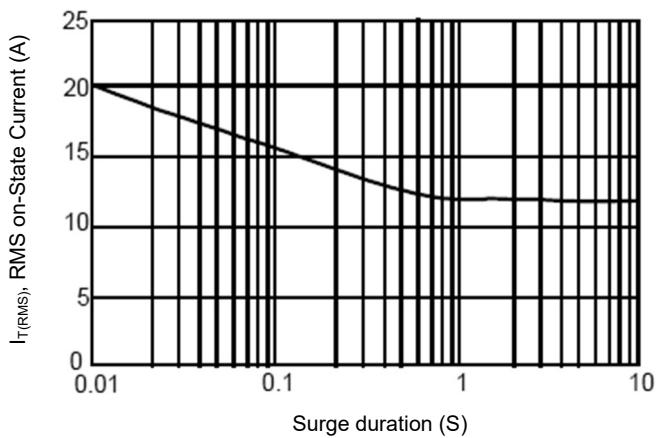
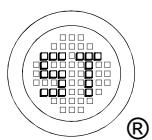
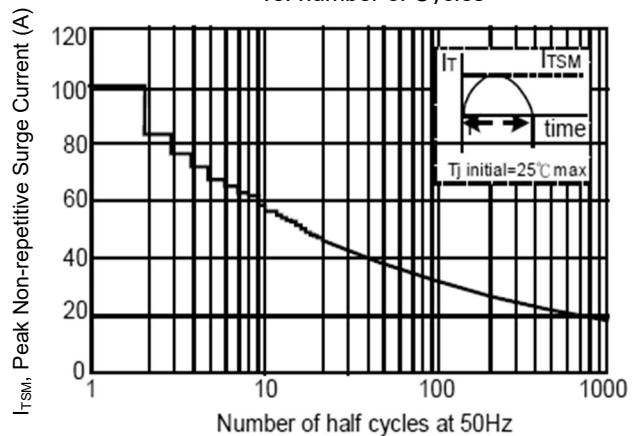


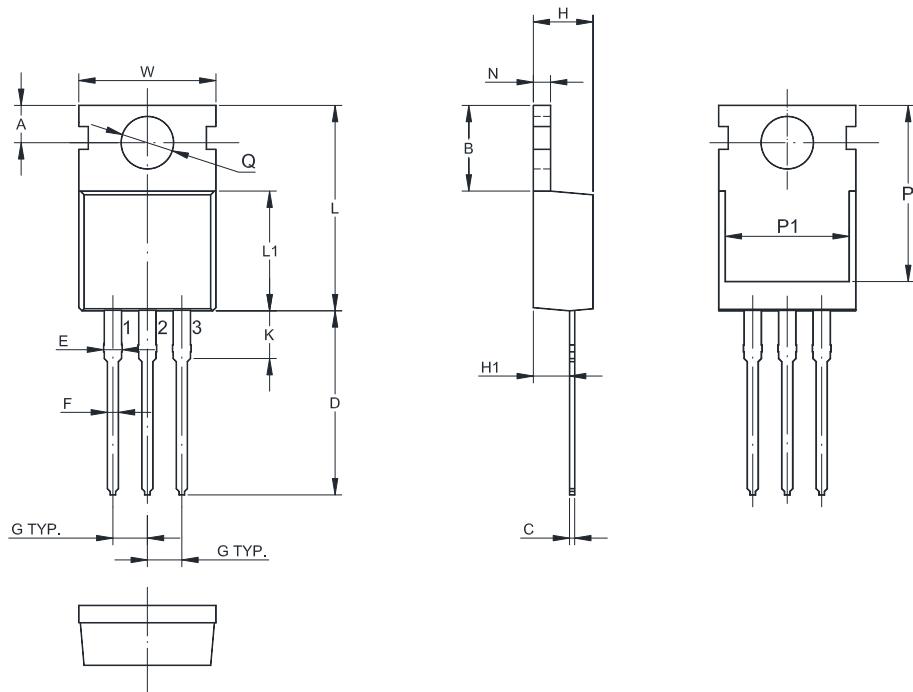
Fig.4 Surge Peak on-State Current vs. number of Cycles



BT12-500-HAF

Package Outline Dimensions (Units: mm)

TO-220FB



| UNIT | A | B | C | D | E | F | G | W | H | H1 | K | L | L1 | N |
|------|-----|-----|-----|----|-----|-----|-------------|------|-----|-----|-----|------|-----|-----|
| mm | 2.9 | 6.8 | 0.7 | 15 | 1.5 | 0.9 | 2.54 TYP | 10.2 | 4.7 | 2.5 | 3.1 | 16.8 | 9.4 | 1.4 |
| | 2.7 | 6.4 | 0.3 | 11 | 1.1 | 0.7 | | 9.8 | 4.3 | 2.2 | 2.7 | 14.8 | 9.0 | 1.2 |

| UNIT | P | P1 | Q |
|------|------|-----|-----|
| mm | 13.3 | 8.2 | 3.7 |
| | 12.7 | 7.6 | 3.5 |

Marking information

" BT12-500 " = Part No.

" ***** " = Date Code Marking

Font type: Arial

